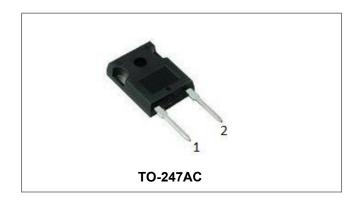






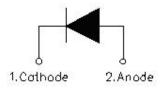
SDUR6030W ULTRAFAST RECTIFIER



Applications

- Antiparallel diode for high frequency switching devices
- Anti saturation diode
- Snubber diode
- Free wheeling diode in converters and motor control circuits
- Rectifiers in switch mode power supplies (SMPS)
- · Inductive heating and melting
- Uninterruptible power supplies (UPS)
- Ultrasonic cleaners and welders

Circuit Diagram



Features

- Ultra-Fast switching
- High current capability
- Low reverse leakage current
- High surge current capability
- Terminals finish: Tin Lead-free plated
- This is a Pb free device
- All SMC parts are traceable to the wafer lot
- Additional testing can be offered upon request

Maximum Ratings(at 25 °C unless otherwise specified)

Characteristics	Symbol	Condition	Max.	Units
Peak Repetitive Reverse Voltage Working Peak Reverse Voltage DC Blocking Voltage	V _{RRM} V _{RWM} V _R	-	300	V
Average Rectified Forward Current	I _{F (AV)}	Tc=105°C, In DC	60	Α
Peak One Cycle Non-Repetitive Surge Current	I _{FSM}	8.3ms, Half Sine pulse	450	А

Electrical Characteristics:

Characteristics	Symbol	Condition	Тур.	Max.	Units
Forward Voltage Drop*	V _{F1}	@ 60A, Pulse, T _J = 25°C	1.14	1.40	V
	V_{F2}	@ 60A, Pulse, T _J = 150°C	-	1.10	V
Reverse Current*	I _{R1}	$@V_R = \text{rated } V_R$ $T_J = 25^{\circ}C$	0.72	10	μΑ
	I _{R2}	$@V_R = \text{ rated } V_R$ $T_J = 125^{\circ}C$	600	1000	uA
Reverse Recovery Time	t _{rr}	I _F =500mA, I _R =1A,and I _m =250mA	43	45	ns

^{*} Pulse width < 300 µs, duty cycle < 2%

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Thermal-Mechanical Specifications:

Characteristics	Symbol	Condition	Specification	Units
Junction Temperature	TJ	-	-55 to +150	°C
Storage Temperature	T _{stg}	-	-55 to +150	°C
Typical Thermal Resistance Junction to Case	$R_{ heta JC}$	DC operation	0.54	°C/W
Approximate Weight	wt	-	6.28	g
Case Style	TO-247AC			

Ratings and Characteristics Curves

Figure1 Typical Forward Characteristics

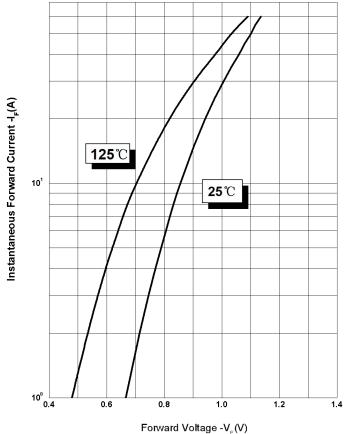


Figure 2 Typical Reverse Characteristics

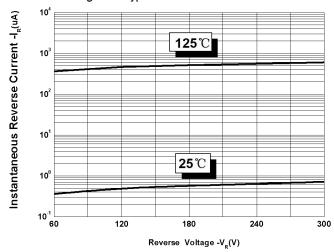
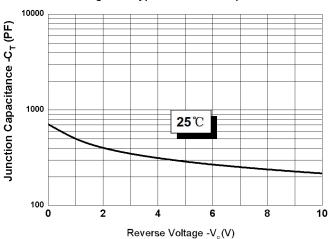


Figure 3 Typical Junction Capacitance



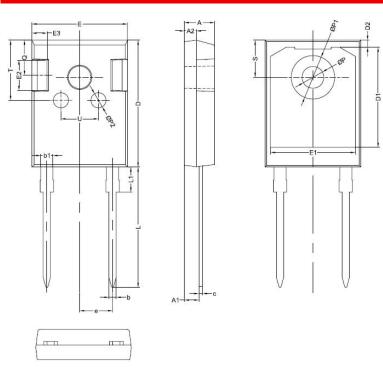
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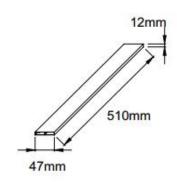


Mechanical Dimensions TO-247AC



OVMDOL	Millimeters				
SYMBOL	MIN.	TYP.	MAX.		
Α	4.80	5.00	5.20		
A1	2.20	2.41	2.61		
A2	1.90	2.00	2.10		
b	1.10	1.20	1.35		
b1	1.80	2.00	2.20		
С	0.50	0.60	0.75		
D	20.30	21.00	21.20		
D1		16.58			
D2		1.17			
E	15.60	15.80	16.00		
E1		14.02			
E2		5.00			
E3		2.50			
е		5.44			
L	19.42	19.92	20.42		
L1		4.13			
P	3.50	3.60	3.70		
P1	7.1	7.19	7.40		
P2		2.50			
Q		5.80			
S	6.05	6.15	6.25		
T		10.00			
U		6.20			
Α	4.80	5.00	5.20		
A1	2.20	2.41	2.61		

Tube Specification



Marking Diagram



Where XXXXX is YYWWL

SDUR = Device Type = Forward Current (60A) = Reverse Voltage (300V) 60 30 W = Configuration

SSG = SSG = Year WW = Week = Lot Number

Cautions: Molding resin

Epoxy resin UL:94V-0

Ordering Information

Device	Package	Shipping	
SDUR6030W	TO-247AC(Pb-Free)	25pcs / tube	

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SDUR6030W





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